

AiT Semiconductor Inc.

DESCRIPTION

The 2SD1628-E, 2SD1628-F, 2SD1628-H and 2SD1628-G are available in the SOT-89 package.

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ORDERING INFORMATION

Package Type	Part Number	
SOT-89	2SD1628-E	
	2SD1628-F	
	2SD1628-H	
	2SD1628-G	
SPQ	1,000pcs/Reel	
AiT provides all RoHS Compliant Products		

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hFE CLASSIFICATION

Rank	Range
E	120 ~ 200
F	160 ~ 320
Н	200 ~ 400
G	280 ~ 560

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^{\circ}C$, unless otherwise specified.

FEATURE

- · Low saturation voltage.
- · Large current capacity.
- High h_{FE} gain.
- · Very small size making it easy to provide high density, small sized hybrid ICs.
- · Halogen free compliance.

APPLICATION

Strobe DC-DC converters, relay drivers, hammer drivers, lamp drivers, motor drivers

PIN DESCRIPTION





1: Base 2: Collector 3: Emitter

SOT-89

PIN#	DESCRIPTION	
1	Base	
2	Collector	
3	Emitter	

V _{CBO} , Collector to Base Voltage	60 V
V _{CEO} , Collector to Emitter Voltage	20 V
V _{EBO} , Emitter to Base Voltage	6 V
I _C , Collector Current-Continuous	5 A
Icp, Collector Current-Continuous	8 A
Pc, Collector Dissipation	0.5 W
TJ, Junction Temperature	150 °C
T _{stg} , Storage Temperature	-55 ~ +150 °C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



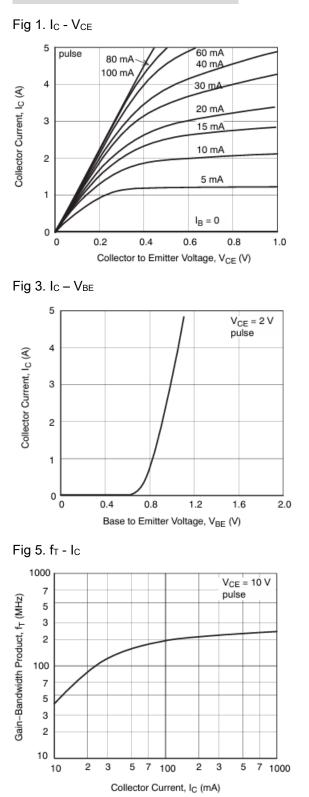
ELECTRICAL CHARACTERISTICS

 $T_A=25^{\circ}C$ unless otherwise specified.

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Collector-Emitter Breakdown voltage	V(BR)CEO	I _C = 10 mA, I _B = 0	20	-	-	V
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C = 100 μA, I _E = 0	60	-	-	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E = 100 μA, I _C = 0	6	-	-	V
Collector Cutoff Current	Ісво	V _{CB} = 50 V, I _E = 0	-	-	100	nA
Emitter Cutoff Current	I _{EBO}	V _{EB} = 5 V, I _E = 0	-	-	100	nA
DC Current Gain	hfe	V _{CE} = 2 V, I _C = 0.5 A	120	-	-	_
		V _{CE} = 2 V, I _C = 3 A	95	-		
Collector-Emitter saturation voltage	V _{CE} (sat)	I _C = 3 A, I _B = 60 mA	-	-	0.5	V
Base-Emitter Saturation Voltage	V _{BE} (sat)	I _C = 3 A, I _B = 60 mA	-	-	1.5	V
Transition Frequency	fT	V _{CE} = 10 V, I _E = 50 A f = 10 MHz	-	120	-	MHz
Output Capacitance	Сов	V _{CB} = 10 V,	-	45	-	pF



TYPICAL CHARACTERISTICS



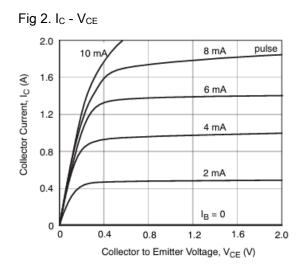


Fig 4. h_{FE} - I_C

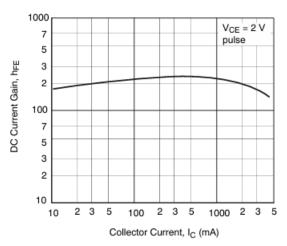
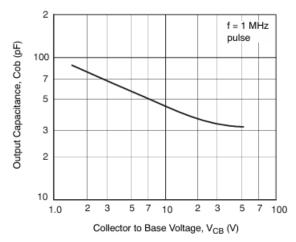


Fig 6. Cob – V_{CB}

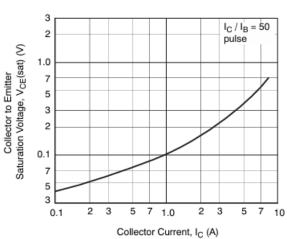




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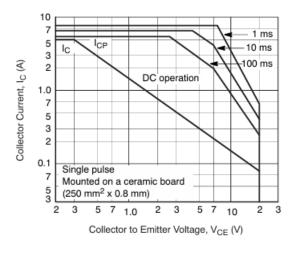
2SD1628 TRANSISTOR SILICON NPN GENERAL PURPOSE TRANSISTOR

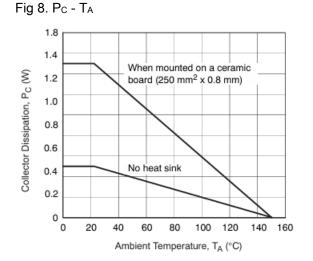




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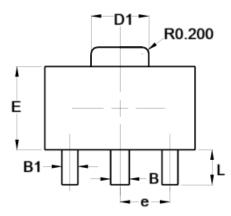


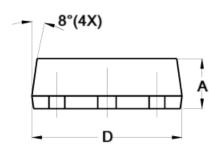


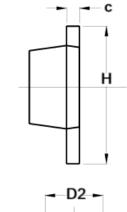


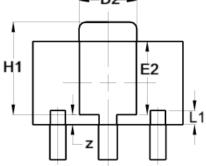
PACKAGE INFORMATION

Dimension in SOT-89 (Unit: mm)









Council al	Millin	neter		
Symbol	Min.	Max.		
А	1.400	1.600		
В	0.500	0.620		
B1	0.420	0.540		
с	0.350	0.430		
D	4.440	4.600		
D1	1.620	1.830		
D2	1.610	1.810		
E	2.400	2.600		
E2	2.050	2.350		
е	1.500 TYP.			
Н	3.950	4.250		
H1	2.630	2.930		
L	0.900	1.200		
L1	0.327	0.527		
Z	0.200	0.400		



IMPORTANT NOTICE

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